IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of

Yoshihito OWA

Application No.: New U.S. Patent Application

Filed: February 23, 2004 Docket No.: 118825

For: NON-VOLATILE SEMICONDUCTOR MEMORY DEVICE AND METHOD OF MANUFACTURING THE SAME

INFORMATION DISCLOSURE STATEMENT

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

Pursuant to 37 CFR §1.56, the attention of the Patent and Trademark Office is hereby directed to the references listed on the attached PTO-1449. Unless otherwise indicated herein, one copy of each reference is attached. It is respectfully requested that the information be expressly considered during the prosecution of this application, and that the references be made of record therein and appear among the "References Cited" on any patent to issue therefrom.

- 1. This Information Disclosure Statement is being filed (a) within three months of the U.S. filing date of this non-CPA application, OR (b) before the mailing date of a first Office Action on the merits in the present application. No certification or fee is required.
- 2. Relevance of the non-English language references is discussed in the present specification. (Refs. 8-9)
- 3. The present application was filed or entered the U.S. National Stage of the PCT after June 30, 2003. In accordance with the June 11, 2003, Notice waiving the requirements of 37 C.F.R. §1.98(a)(2)(i), copies of any U.S. patents and patent application publications are not attached. (Refs. 1-7)
- English-language Abstracts of the non-English language references are attached hereto. (Refs. 8-9)
- 5. A computer-generated English translation of the following Japanese Patent Publication has been obtained from the website of the Japanese Patent Office ([http://www.jpo.go.jp]), and is attached, but has not been reviewed for accuracy. See Reference 8.

8 Reference 9 corresponds to reference 4, therefore a translation is not attached.

Respectfully submitted,

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Form PTO-1449 (REV. 8-83)	•			ATTY DOCKET NO. 118825			APPLICATION NO. New U.S. Patent Application		
INFORMATION DISCLOSURE STATEMENT									
(Use several sheets if necessary)				APPLICANT Yoshihito OWA					
				FILING DATE February 23, 2004					
		U.S.	PATE	ENT DOCU		- -			
EXAMINER INITIAL		DOCUMENT NUMBER	DATE 07/03/2001 06/19/2001 01/23/2001 10/19/1999 02/27/1996 06/06/1995 04/18/1995		NAME		CLASS	SUB CLASS	
	1	US 6,255,166 B1			OGURA et al.				
	2	US 6,248,633 B1			OGURA et al.				
	3	US 6,177,318 B1			OGURA et al.				
	4	5,969,383			CHANG et al.				
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	6	5,422,504			CHANG et al.				
	7	5,408,115			CHANG				
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		DOCUMENT NUMBER	DATE 06/28/1994 03/16/1999 09/10/1999 06/08/2001		COUNTRY		CLASS	SUB CLASS	
	8	JP A 6-181319 w/ abst & trans			Japan				
	9	JP A 11-074389 w/ abst			Japan				
	10	JP B1 2978477 w/ trans			Japan				
	11	JP A 2001-156188 w/ trans			Japan				
	12	JP A 7-161851 w/ trans	06/	/23/1995	Japan				
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		Technical Papers, 2000 IEEE Chang, Kuo-Tung et al. "A New SONOS Memory Using Source-Side Injection for Programming." IEEE Electron Device							
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		Letters, Vol. 19 No. 7 (pp. 253-254) July 1998							
	15	Chen, Wei-Ming et al. "A Novel Flash Memory Device with SPlit Gate Source Side Injection and ONO Charge Storage Stack (SPIN)." 1997 Symposium on VLSI Technology Digest of Technical Papers (pp. 63-64)							
EXAMINER	EXAMINER DATE CONSIDERED								
		f citation considered, whether or not considered, include conv				aw line t	hrough citat	ion if not in	

Date: February 23, 2004